TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

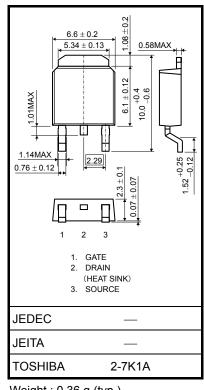
TK4P60DB

Switching Regulator Applications

- Low drain-source ON-resistance: RDS (ON) = 1.6 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 2.2 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A (max) (V_{DS} = 600 \ V)$
- Enhancement-mode: $V_{th} = 2.4$ to 4.4 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	600	V
Gate-source voltage		V _{GSS}	±30	V
Drain current	DC (Note 1)	I _D	3.7	
	Pulse (t = 1 ms) (Note 1)	I _{DP}	14.8	A
Drain power dissipati	on (Tc = 25°C)	PD	80	W
Single pulse avalanche energy (Note 2)		E _{AS}	147	mJ
Avalanche current		I _{AR}	3.7	А
Repetitive avalanche energy (Note 3)		E _{AR}	8	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C



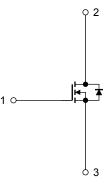
Weight : 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	1.56	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	125	°C/W	

Note 1: Please use devices on conditions that the channel temperature is below 150°C. Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 18.7 mH, R_G = 25 Ω , I_{AR} = 3.7 A Note 3: Repetitive rating: pulse width limited by maximum channel temperature This transistor is an electrostatic sensitive device. Please handle with caution.



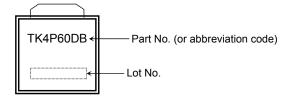
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off currer	nt	I _{DSS}	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600			V
Gate threshold vol	tage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4	—	4.4	V
Drain-source ON-r	esistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.9 \text{ A}$	_	1.6	2.0	Ω
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1.9 \text{ A}$	0.6	2.2	_	S
Input capacitance		C _{iss}			540	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		3	_	
Output capacitance		C _{oss}	1	_	60	_	
Switching time	Rise time	tr	$V_{GS} = 1.9.A V_{OUT}$ $V_{GS} = 1.9.A V_{OUT}$ $R_{L} = 105 \Omega$ $Duty \le 1\%, t_{W} = 10 \ \mu s$ $V_{DD} \approx 200 \ V$	_	18		ns
	Turn-on time	t _{on}			40		
	Fall time	t _f			8	_	
	Turn-off time	t _{off}		_	55	_	
Total gate charge		Qg		—	11		nC
Gate-source charge		Q _{gs}	$V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=3.7~A$	_	6		
Gate-drain charge		Q _{gd}	1	_	5		

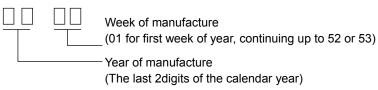
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	3.7	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_		14.8	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 3.7 A, V _{GS} = 0 V	_		-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 3.7 \text{ A}, V_{GS} = 0 \text{ V},$	_	1000	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	5.5	_	μC

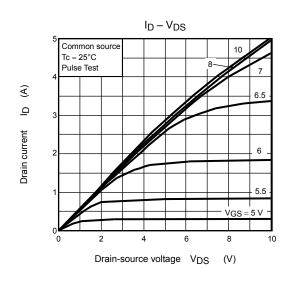
Marking (Note 4)

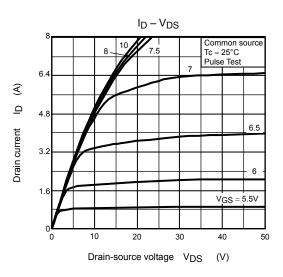


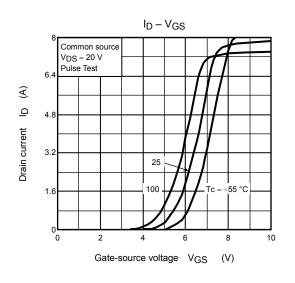
Note 4: * Weekly code: (Four digits)

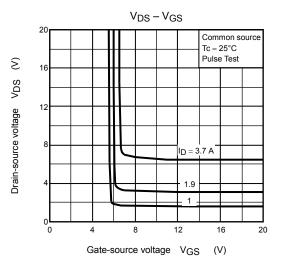


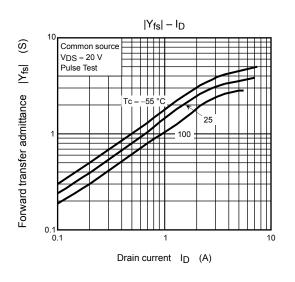
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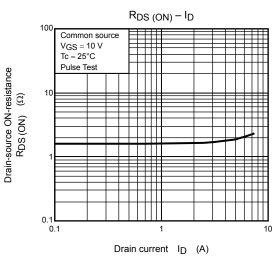




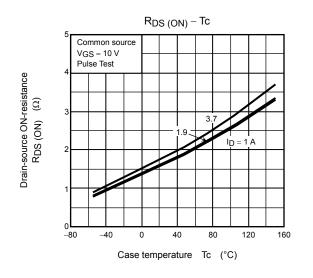


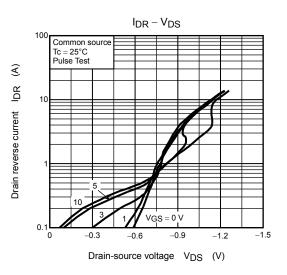


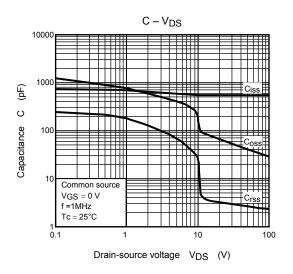


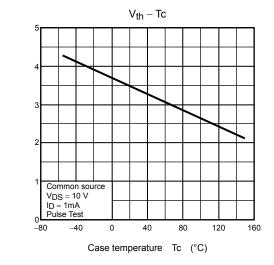


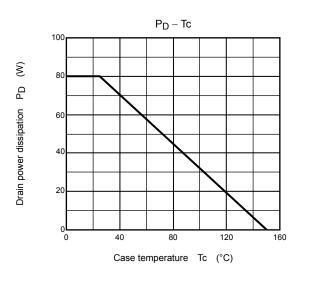
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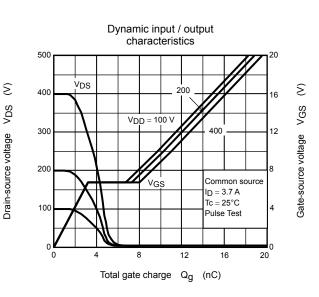








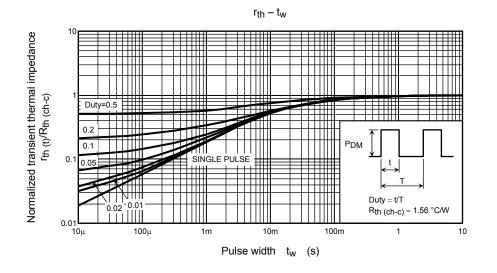




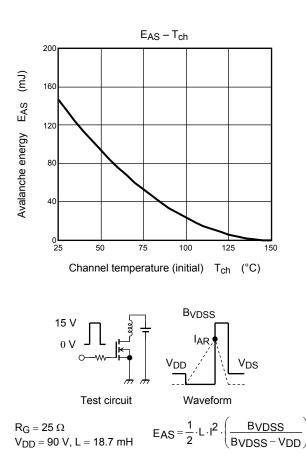
S

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Gate threshold voltage



SAFE OPERATING AREA 100 (pulsed) * ID max П 10 100 μ ID max (continuous) Drain current I_D (A) DC operation Tc = 25°C 0.1 ТП 0.01 * Single pulse Tc=25°C Curves must be derated linearly with increase in temperature. /DSS 0.001 1 10 100 1000 Drain-source voltage V_{DS} (V)



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